

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXFH230N10T

FEATURES

- Drain Source Voltage-
- : V_{DSS}= 100V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 3m Ω (Max)
- Fast Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

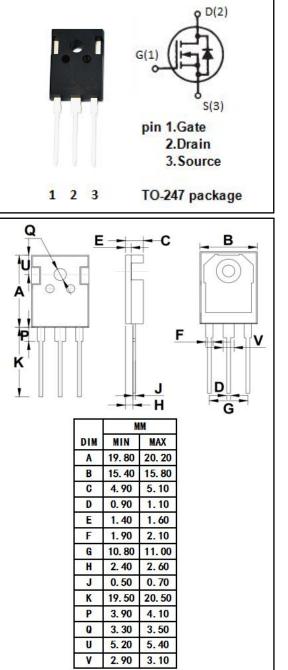
APPLICATIONS

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- AC and DC Motor Drives
- Robotics and Servo Controls

ABSOLUTE MAXIMUM RATINGS(T_a=25°C) SYMBOL VALUE PARAMETER UNIT Drain-Source Voltage 100 V VDSS Gate-Source Voltage-Continuous ± 20 V V_{GS} **Drain Current-Continuous** 230 I_{D} А **Drain Current-Single Plused** 500 A **I**DM P_D Total Dissipation @T_C=25℃ 650 W °C Τį Max. Operating Junction Temperature -55~175 Storage Temperature -55~175 °C Tstg

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.23	°C/W



isc website: <u>www.iscsemi.com</u>



isc N-Channel MOSFET Transistor

IXFH230N10T

• ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =1mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 115A			3	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±200	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =100V; V _{GS} = 0 V _{DS} =100V; V _{GS} = 0;TJ=150°C			50 3000	μA
V _{SD}	Diode Forward On-voltage	I _F = 100A ;V _{GS} = 0			1.3	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.